

View Online at <https://aerobasegroup.com/nsn/5961-01-419-4623>

Inclosure Material:

Ceramic all semiconductor device diode and metal all semiconductor device diode

Overall Length:

0.205 inches all semiconductor device diode and 0.225 inches all semiconductor device diode

Overall Diameter:

0.119 inches all semiconductor device diode and 0.124 inches all semiconductor device diode

End Application:

Jtids

Component Function Relationship:

Matched

Component Name And Quantity:

4 semiconductor device diode

Mounting Method:

Press fit all semiconductor device diode

Field Force Effect Type:

Electrostatic charge

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

35.0 breakdown voltage, dc all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius junction all semiconductor device diode

Test Data Document:

13499-952-6557-001 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 case all semiconductor device diode

Specification Data:

13499-353-3793 manufacturers specification

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0